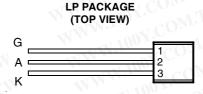
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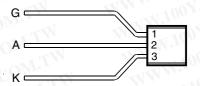
- 2 A Continuous On-State Current
- 15 A Surge-Current
- Glass Passivated Wafer
- 400 V to 600 V Off-State Voltage
- Max I_{GT} of 200 μA
- Package Options

PACKAGE	PACKING	PART # SUFFIX			
LP	Bulk	(None)			
LP with fomed leads	Tape and Reel	R			



MDC1AA





MDC1AB

absolute maximum ratings over operating case temperature (unless otherwise noted)

RATING			VALUE	UNIT	
Repetitive peak off-state voltage (see Note 1)	TICP106D TICP106M	V_{DRM}	400 600	V)	
Repetitive peak reverse voltage TICP106D TICP106M			400 600	VV	
Continuous on-state current at (or below) 25°C case temperature (see Note 2)			2	Α	
Surge on-state current (see Note 3)			15	Α	
Peak positive gate current (pulse width ≤ 300 μs)			0.2	Α	
Average gate power dissipation (see Note 4)		P _{G(AV)}	0.3	W	
Operating case temperature range		T _C	-40 to +110	°C	
Storage temperature range		T _{stg}	-40 to +125	°C	
Lead temperature 3.2 mm from case for 10 seconds		TL CO	230	°C	

NOTES: 1. These values apply when the gate-cathode resistance R_{GK} = 1 $k\Omega$.

- 2. These values apply for continuous dc operation with resistive load. Above 25°C derate linearly to zero at 110°C.
- 3. This value applies for one 50 Hz half-sine-wave when the device is operating at (or below) the rated value of peak reverse voltage and on-state current. Surge may be repeated after the device has returned to original thermal equilibrium.
- 4. This value applies for a maximum averaging time of 20 ms.

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electrical characteristics at 25°C case temperature (unless otherwise noted)

PARAMETER		TEST CONDITIONS			MIN	TYP	MAX	UNIT
I _{DRM}	Repetitive peak off-state current	V _D = rated V _{DRM}	$R_{GK} = 1 k\Omega$	MITW WW	W.10	ov.C	20	μА
I _{RRM}	Repetitive peak reverse current	V _R = rated V _{RRM}	I _G = 0	OM:TW W	WW.	1007.	200	μА
I _{GT}	Gate trigger current	V _{AA} = 12 V	$R_L = 100 \Omega$	t _{p(g)} ≥ 20 μs		5	200	μΑ
V _{GT}	Gate trigger voltage	V _{AA} = 12 V	$R_L = 100 \Omega$ $R_{GK} = 1 k\Omega$	t _{p(g)} ≥ 20 μs	0.4	N.100	1 1 1 CC	V
I _H	Holding current	V _{AA} = 12 V	$R_{GK} = 1 k\Omega$	Initiating I _T = 10 mA	At a	XV 10	5	mA
V _T	On-state voltage	I _T = 1 A	(see Note 5)	V.CO.	WV		1.5	V

NOTE 5: This parameter must be measured using pulse techniques, t_p = 1 ms, duty cycle ≤ 2 %. Voltage sensing-contacts, separate from the current carrying contacts, are located within 3.2 mm from the device body.

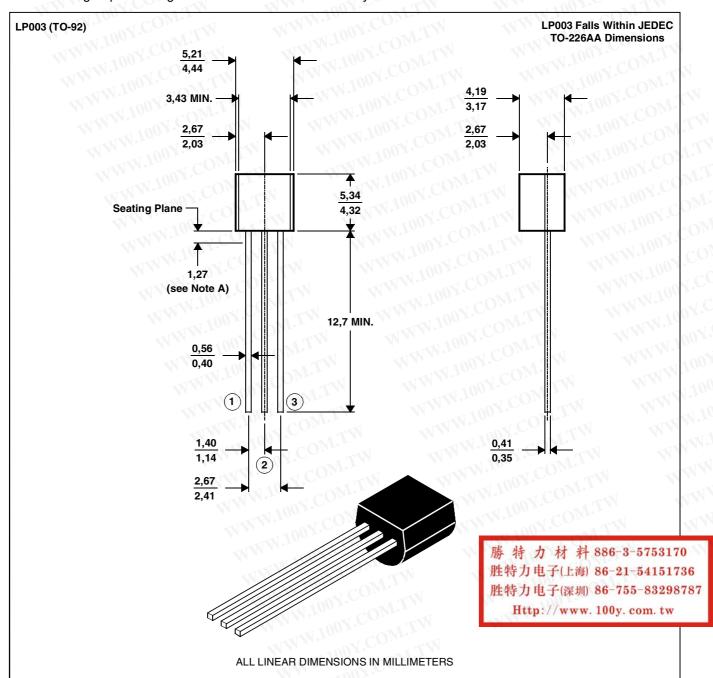
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MECHANICAL DATA

LP003 (TO-92) 3-pin cylindical plastic package

This single-in-line package consists of a circuit mounted on a lead frame and encapsulated within a plastic compound. The compound will withstand soldering temperature with no deformation, and circuit performance characteristics will remain stable when operated in high humidity conditions. Leads require no additional cleaning or processing when used in soldered assembly.



NOTE A: Lead dimensions are not controlled in this area.

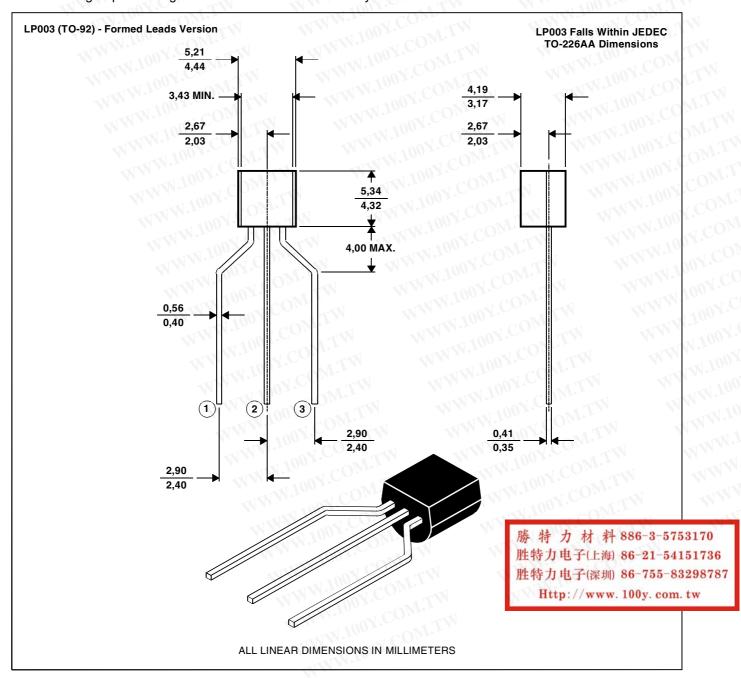
MDXXAX

MECHANICAL DATA

LP003 (TO-92)

3-pin cylindical plastic package

This single-in-line package consists of a circuit mounted on a lead frame and encapsulated within a plastic compound. The compound will withstand soldering temperature with no deformation, and circuit performance characteristics will remain stable when operated in high humidity conditions. Leads require no additional cleaning or processing when used in soldered assembly.

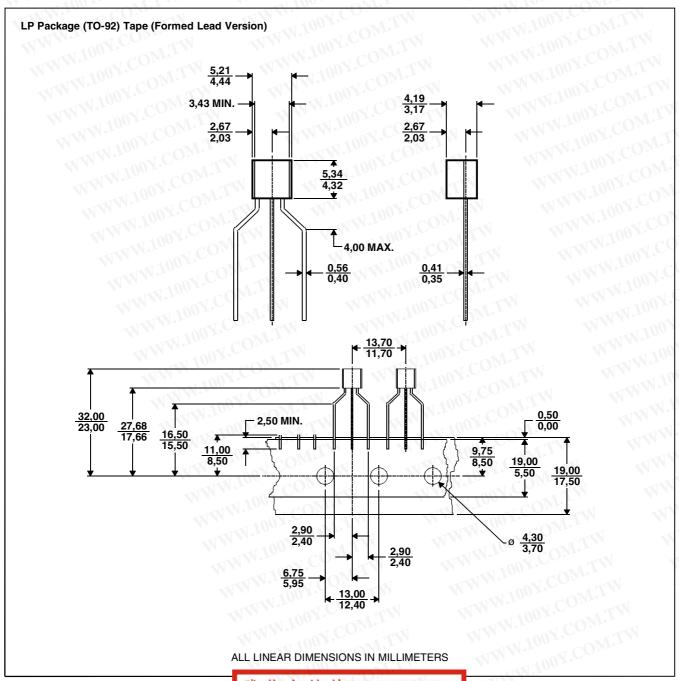


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MECHANICAL DATA

LPR tape dimensions



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